TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA8127NG, TA8127FG

3V AM / FM 1chip Tuner IC

TA8127NG and TA8127FG are the AM / FM 1chip tuner ICs, which are designed for portable radios and 3V headphone radios.

Features

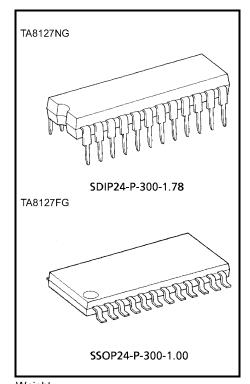
• Built-in

FM F / E, AM / FM IF and FM MPX

- AM detector coil and IF coupling condenser are not needed.
- Compact package

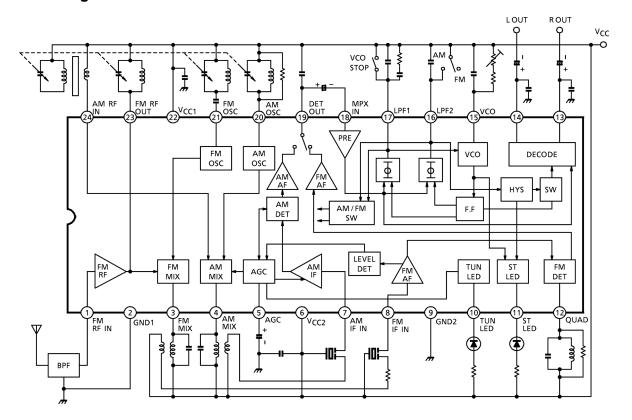
TA8127NG: Shrink DIP 24 pin (1.78mm pitch) TA8127FG: Mini flat packge 24 pin

• Operating supply voltage range $V_{CC} = 1.8 \sim 7.0 V (Ta = 25 \circ C)$



Weight SDIP24-P-300-1.78: 1.2g (typ.) SSOP24-P-300-1.00: 0.31 (typ.)

Block Diagram



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Explanation Of Terminals

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)		
			AM	FM	
1	FM-RF IN	0	0.7		
2	GND1 (GND for RF stage)	_	0	0	
3	FM MIX	(S)	3.0	3.0	
4	AM MIX	V _{CC1} (22) (4) (5) (6) (7) (7) (8) (9) (9) (10) (3.0	3.0	
5	AGC (AM AGC)	IF AGC S RF AGC GND2 9			
6	V _{CC2} (V _{CC} for IF / MPX stage)	-	3.0	3.0	
7	AM IF IN	VCC2 6 C K K K K K K K K K K K K K K K K K K	3.0	3.0	
8	FM IF IN	V _{CC2} 6 8 GND2 9	3.0	3.0	

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)		
1 11110.	icii	menu onout	AM	FM	
9	GND2 (GND for IF / MPX stage)	_	0	0	
10	TUN LED (tuning LED)	VCC2 6 10 GND2 9	_	-	
11	ST LED (stereo LED)	76kHz ————————————————————————————————————	-	1	
12	QUAD (FM QUAD. Detector)	V _{CC2} 6	3.0	3.0	
13 14	R-OUT (R-ch output) L-OUT (L-ch output)	VCC2 6 GND2 9 GND2 9	1.0	1.0	
15	VCO	VCC2 6 AMP GND2 9	2.5	2.5 (VCO stop mode)	
16	LPF2 • LPF terminal for synchronous detector • Bias terminal for AM / FM SW circuit $V_{16} = V_{CC} \rightarrow AM (VCO stop)$ $V_{16} = OPEN \rightarrow FM$	GND2 9	3.0	2.2 (VCO stop mode 2.7)	
17	LPF1 • LPF terminal for phase detector • VCO stop terminal V ₇ = V _{CC} →VCO stop	GND2 9	2.7	2.2	

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)		
1	i.c.iii	monal should	AM	FM	
18	MPX IN	(B) (G) (D) (D) (D) (D) (D) (D) (D) (D) (D) (D	0.7	0.7	
19	DET OUT	VCC2 (6) AM O FM O B B B B B B B B B B B B B	1.5	1.2	
20	AM OSC	V _{CC1} 20 MIX	3.0	3.0	
21	FM OSC	V _{CC1} (22) (21) MIX - II -	3.0	3.0	
22	V _{CC1} (V _{CC} for RF stage)	_	3.0	3.0	
23	FM RF OUT	Cf. Pin(1)	3.0	3.0	
24	AM RF IN	V _{CC1} 22 24 GND1 2	3.0	3.0	



Absolute Maximum Ratings (Ta = 25°C)

Characteris	stic	Symbol	Rating	Unit
Supply voltage		V _{CC}	8	V
LED current		I _{LED}	10	mA
LED voltage		V_{LED}	8	V
Power dissipation	TA8127NG	PD	1200	mW
Power dissipation	TA8127FG	(Note)	400	IIIVV
Operating temperature		T _{opr}	-25~75	°C
Storage temperature		T _{stg}	-55~150	°C

Note: Derated above 25°C in the proportion of 9.6mW / °C for TA8127NG and of 3.2mW / °C for TA8127FG.



Electrical Characteristics

Unless Otherwise Specified,

Ta = 25°C, V_{CC} = 3V, F / E: f = 83MHz, f_m = 1kHz FM IF: f = 10.7MHz, Δf = ±22.5kHz, f_m = 1kHz AM: f = 1MHz, MOD = 30%, f_m = 1kHz MPX: f_m = 1kHz

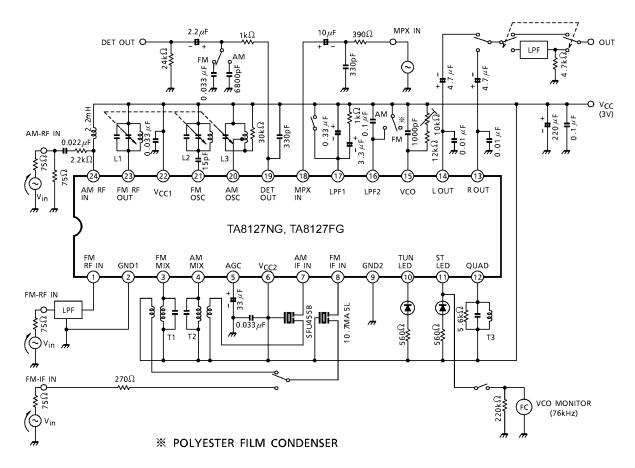
Characteristic		Symbol	Test Cir- cuit	Test Condition	Min.	Тур.	Max.	Unit	
Sunni	y current	I _{CC (FM)}	1	V _{in} = 0, FM mode	_	13.2	20.0	mA	
Suppi	y current	I _{CC (AM)}	1	V _{in} = 0, AM mode	_	8.4	13.5	ША	
F/E	Input limiting voltage	V _{in (lim.)}	1	– 3dB limiting	_	10.0	_	dBµV EMF	
F / E	Local OSC voltage	Vosc	2	f _{OSC} = 72.3MHz	_	105	_	mV _{rms}	
	Input limiting voltage	V _{in (lim.)} IF	1	– 3dB limiting	40	46	53	dBµV EMF	
	Rcovered output voltage	overed output voltage V _{OD}		V _{in} = 80dBµV EMF	55	80	110	mV _{rms}	
FM IF	Signal to noise ratio	S/N	1	V _{in} = 80dBμV EMF	_	70	_	dB	
IIF	Total harmonic distortion	THD	1	V _{in} = 80dBμV EMF	_	0.4	_	%	
	AM rejection ratio	AMR		V _{in} = 80dBµV EMF	_	32	_	dB	
	Lamp on sensitivity	VL	1	I _L = 1mA	45	51	56	dBµV EMF	
	Gain	G _V	1	V _{in} = 26dBµV EMF	40	70	110	mV _{rms}	
	Recovered output voltage	V _{OD}	1	V _{in} = 60dBµV EMF	55	80	110		
AM	Signal to noise ratio	S/N	1	V _{in} = 60dBμV EMF	_	42	_	dB	
	Total harmonic distortion	THD	1	V _{in} = 60dBµV EMF	_	1.0	_	%	
	Lamp on sensitivity	VL	1	I _L = 1mA	20	25	30	dBµV EMF	
Pin(19) output resistance		0)	_	FM mode	_	0.75	- 40		
riii(I	o) output resistance	R ₁₉	1	AM mode	_	12.5	_	· kΩ	

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Characteristic			Symbol	Test Cir- cuit	Test Condition		Min.	Тур.	Max.	Unit		
	Input resistance		R _{IN}	_	-	_		24	_	kΩ		
	Output resista	ince	R _{OUT}	_	-	_	_	5	_	V77		
	Max. Composite signal input voltage		V _{in (max.)} stereo	1	L+R = 90%, P = 10% f _m = 1kHz, THD = 3%					350	_	mV _{rms}
	Separation				L+R =	f _m = 100Hz	_	42	_			
			Sep	1	135mV _{rms}	f _m = 1kHz	35	42	_	dB		
					P = 15mV _{rms}	f _m = 10kHz	_	42	_			
	Total harmonic distortion	Monaural	THD (monaural)	1	V _{in} = 150mV _{rms}		_	0.2	_	%		
MPX		Stereo	THD (stereo)	1	L+R = 135mV _{rms} , P = 15mV _{rms}		_	0.2	_	70		
	Voltage gain		G _{V (MPX)}	1	V _{in} = 150mV _{rms}		-5	-3	-1	dB		
	Channel balance		C. B.	1	V _{in} = 150mV _{rms}		-2	0	2	uБ		
	Stereo lamp	On	V _{L (ON)}	1	Pilot input		_	8	16	mV _{rms}		
	sensitivity	Off	V _{L (OFF)}	'	Pilot input		2	6		iii v rms		
	Stereo lamp hysteresis		V _H	1	To LED turn of LED turn on	from	_	2	_	mV _{rms}		
	Caputure range		C. R.	1	P = 15mV _{rms}		_	±3	_	%		
	Signal to noise ratio		S/N	1	V _{in} = 150mV _{rm}	S	_	70	_	dB		

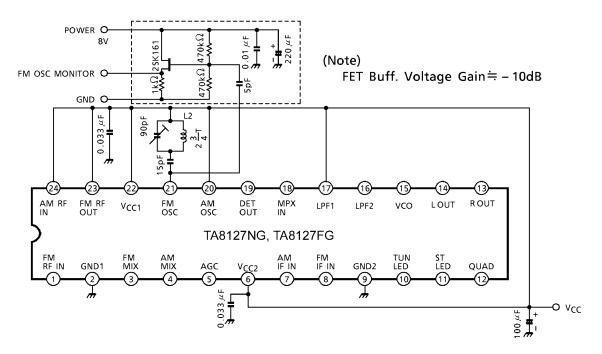
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Test Circuit 1



Using other types of condensers, there are some cases that the MPX does not do normal stereo action at high temperature or low temperature.

Test Circuit 2



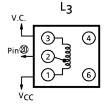
Coil Data

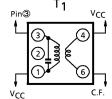
Coil No.	Test	L	Co	QO			Turns		Wire	Reference	
COII NO.	Freq. (Hz)	(µH)	(pF)	QΩ	1–2	2–3	1–3	1–4	4–6	(mmφ)	Reference
L ₁ FM RF	100M	_		100	ı			$2\frac{1}{2}$	_	0.5UEW	(S) 53T-037-202
L ₂ FM OSC	100M	_		100		_	$2\frac{3}{4}$	_	_	0.5UEW	(S) 0258–244
L ₃ AM OSC	796k	288	_	115	13	73	_	_	_	0.08UEW	(S) 4147-1356-038
T ₁ FM MIX	10.7M	_	75	100	_	_	13	_	2	0.1UEW	(S) 2153-414-041
T ₂ AM MIX	455k	_	180	120	_	_	180	_	15	0.08UEW	(S) 2150-2162-165
T ₃ FM DET	10.7M	_	47	165	_	_	16	_	_	0.09UEW	(S) 2153-4095-122

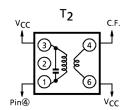
(S): SUMIDA electric CO., LTD











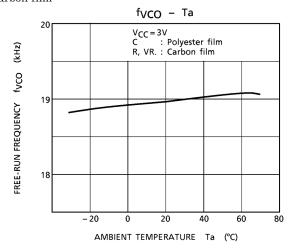


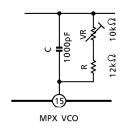
Hint On Use Of TA8127NG And TA8127FG

External parts of MPX VCO

(1) Temperature characteristic of MPX VCO free –run frequency. The temperature characteristic of MPX VCO is shown in the diagram as below. Select one with a better temperature characteristic (C, R and VR.) in use. We recommend,

C : Polyester film R, VR: Carbon film





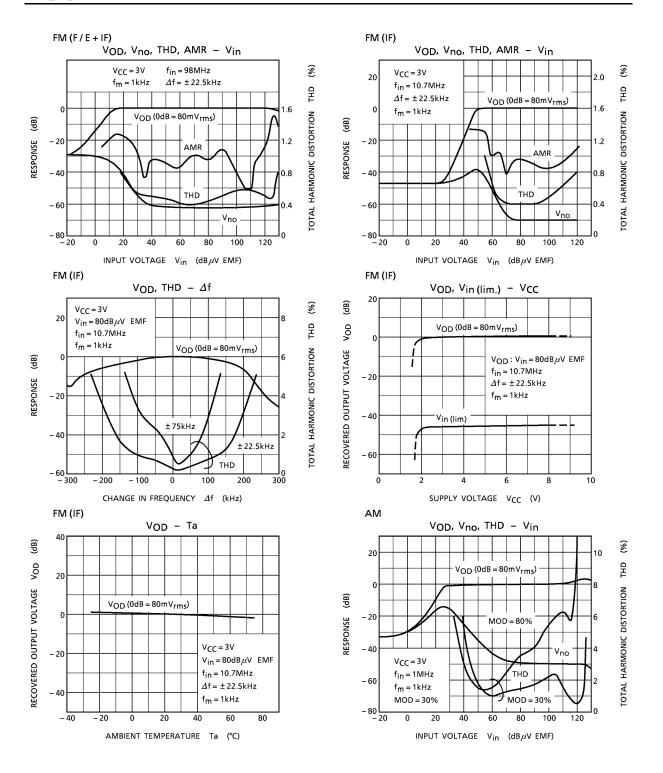
(2) Value of the external parts

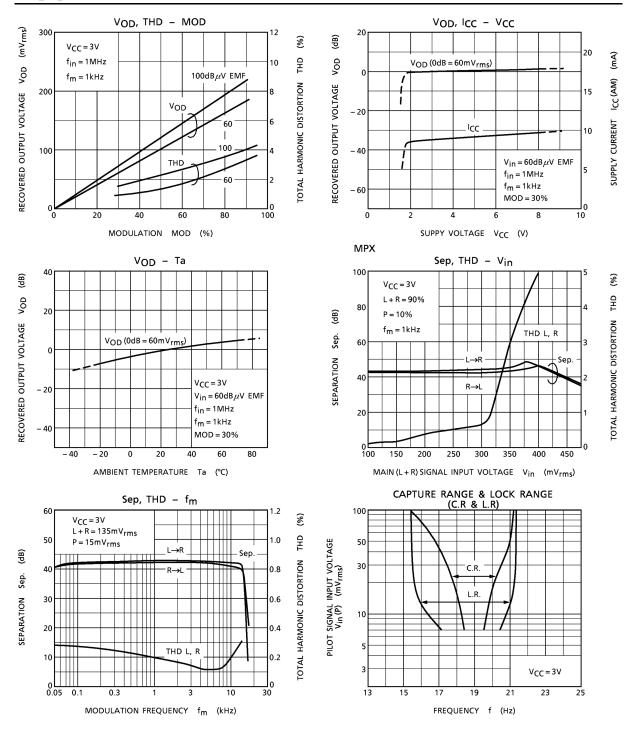
We recommend to set up these value as below.

 $R = 12k\Omega$

 $\mathrm{VR}=10\mathrm{k}\Omega$

C = 1000pF

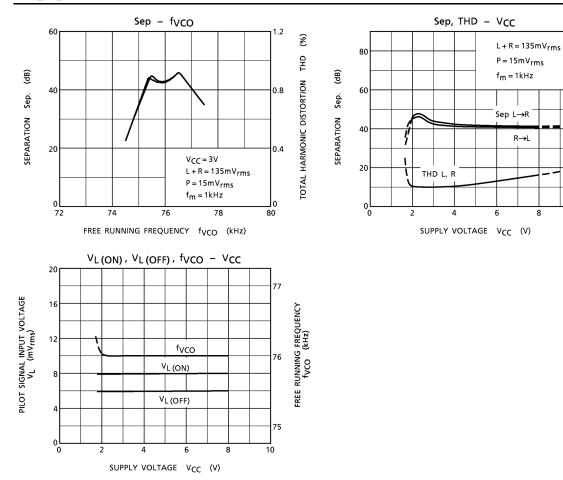




(%)

TOTAL HARMONIC DISTORTION THD

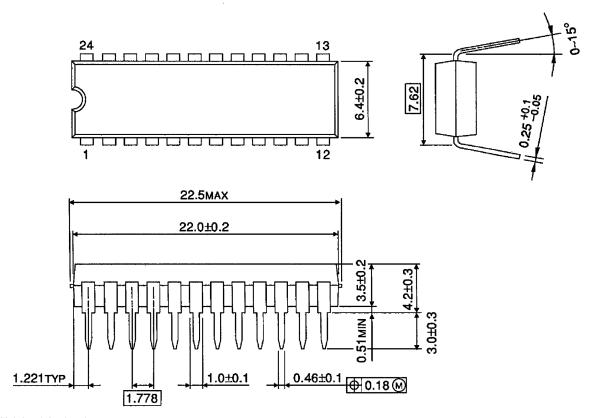
_|ე 10



Package Dimensions

SDIP24-P-300-1.78

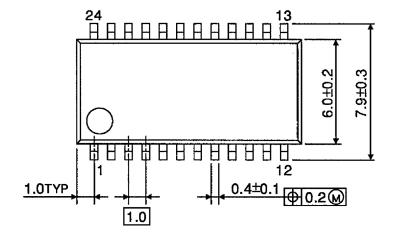


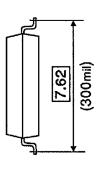


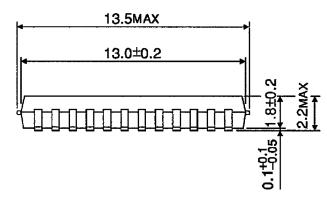
Weight: 1.2g (typ.)

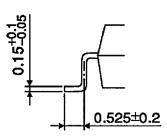
Package Dimensions

SSOP24-P-300-1.00 Unit: mm









Weight: 0.31g (typ.)

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About solderability, following conditions were confirmed

- Solderability
 - (1) Use of Sn-37Pb solder Bath
 - · solder bath temperature = 230°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux
 - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - · solder bath temperature = 245°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux